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### Vishay Semiconductors

# Hyperfast Rectifier, 15 A FRED Pt®



PRIMARY CHARACTERISTICS									
I <sub>F(AV)</sub>	15 A								
$V_{R}$	600 V								
V <sub>F</sub> at I <sub>F</sub>	1.55 V								
t <sub>rr</sub> (typ.)	18 ns								
T <sub>J</sub> max.	175 °C								
Package	TO-220AC 2L								
Circuit configuration	Single								

#### **FEATURES**

- Hyperfast recovery time, extremely low Q<sub>rr</sub>
- Low forward voltage drop
- 175 °C operating junction temperature
- Low leakage current
- True 2 pin package
- Designed and qualified according to JEDEC®-JESD 47
- Material categorization: for definitions of compliance please see <a href="https://www.vishav.com/doc?99912">www.vishav.com/doc?99912</a>

#### **DESCRIPTION / APPLICATIONS**

State of the art hyperfast recovery rectifiers designed with optimized performance of forward voltage drop, hyperfast recovery time, and soft recovery.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in PFC boost stage in the AC/DC section of SMPS, inverters or as freewheeling diodes.

The extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

ABSOLUTE MAXIMUM RATINGS										
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS						
Peak repetitive reverse voltage	$V_{RRM}$		600	V						
Average rectified forward current in DC	I <sub>F(AV)</sub>	T <sub>C</sub> = 141 °C	15	۸						
Non-repetitive peak surge current	I <sub>FSM</sub>	T <sub>J</sub> = 25 °C	120	Α						
Operating junction and storage temperatures	T <sub>J</sub> , T <sub>Stg</sub>		-65 to +175	°C						

<b>ELECTRICAL SPECIFICATIONS</b> (T <sub>J</sub> = 25 °C unless otherwise specified)										
PARAMETER	ARAMETER SYMBOL TEST CONDITIONS									
Breakdown voltage, blocking voltage	V <sub>BR</sub> , V <sub>R</sub>	Ι <sub>R</sub> = 100 μΑ	600	-	-					
Forward voltage	V	I <sub>F</sub> = 15 A	-	2.5	3.4	4 V				
	V <sub>F</sub>	I <sub>F</sub> = 15 A, T <sub>J</sub> = 150 °C	-	1.55	2					
Davaras laskana aurrent		$V_R = V_R$ rated	-	0.02	36					
Reverse leakage current	I <sub>R</sub>	T <sub>J</sub> = 150 °C, V <sub>R</sub> = V <sub>R</sub> rated	-	40	250	- μΑ				
Junction capacitance	C <sub>T</sub>	V <sub>R</sub> = 600 V	-	12	=	pF				
Series inductance	L <sub>S</sub>	Measured lead to lead 5 mm from package body	-	8	-	nH				



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<b>DYNAMIC RECOVERY CHARACTERISTICS</b> (T <sub>J</sub> = 25 °C unless otherwise specified)									
PARAMETER	SYMBOL	TEST	CONDITIONS	MIN.	TYP.	MAX.	UNITS		
		$I_F = 1 A, dI_F/dt = 1$	$I_F = 1 \text{ A}, dI_F/dt = 100 \text{ A/}\mu\text{s}, V_R = 30 \text{ V}$			23			
Doverse recovery time		$I_F = 15 \text{ A}, dI_F/dt =$	$I_F = 15 \text{ A}, dI_F/dt = 100 \text{ A/}\mu\text{s}, V_R = 30 \text{ V}$			30	no		
Reverse recovery time	t <sub>rr</sub>	T <sub>J</sub> = 25 °C		-	20	-	ns		
		T <sub>J</sub> = 125 °C		-	45	-			
- ·		T <sub>J</sub> = 25 °C	I <sub>F</sub> = 15 A,	-	2.7	-	- A - nC		
Peak recovery current	I <sub>RRM</sub>	T <sub>J</sub> = 125 °C	$dI_F/dt = 200 \text{ A/}\mu\text{s},$ $V_R = 390 \text{ V}$	-	5.5	-			
Davis and a second and a second	0	T <sub>J</sub> = 25 °C	" " " " " " " " " " " " " " " " " " " "	-	26	-			
Reverse recovery charge	Q <sub>rr</sub>	T <sub>J</sub> = 125 °C		-	130	-			
Reverse recovery time	t <sub>rr</sub>		I <sub>E</sub> = 15 A,	-	32	-	ns		
Peak recovery current	I <sub>RRM</sub>	T <sub>J</sub> = 125 °C	' '		17	-	Α		
Reverse recovery charge	$Q_{rr}$	1	-	290	-	nC			

THERMAL - MECHANICAL SPECIFICATIONS										
PARAMETER SYMBOL		TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS				
Maximum junction and storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>		-65	-	175	°C				
Thermal resistance,	В		-	1.2	1.4					
junction-to-case	R <sub>thJC</sub>		-	3.7	4.3					
Thermal resistance, junction to ambient	R <sub>thJA</sub>	Typical socket mount	-	-	70	°C/W				
Typical thermal resistance, case to heatsink			-	0.5	-					
Weight			-	2	-	g				
Weight			-	0.07	-	oz.				
Mounting torque			6 (5)	-	12 (10)	kgf · cm (lbf · in)				
Marking device		Case style TO-220AC 2L	ETX1506							



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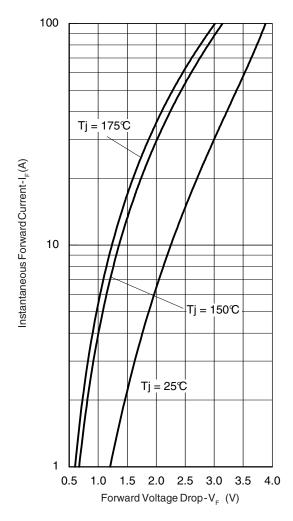


Fig. 1 - Typical Forward Voltage Drop Characteristics

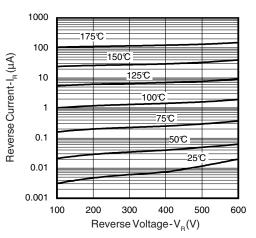


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

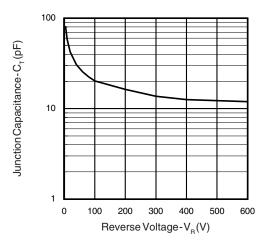


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

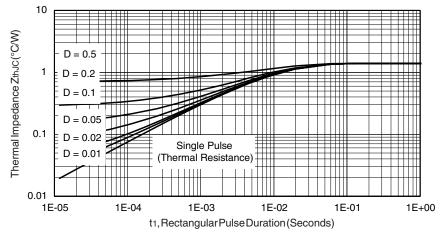


Fig. 4 - Maximum Thermal Impedance Z<sub>thJC</sub> Characteristics

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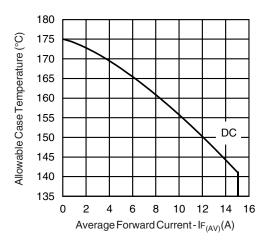


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

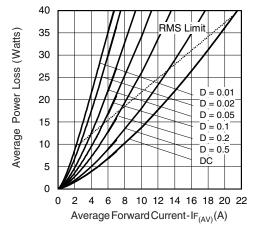


Fig. 6 - Forward Power Loss Characteristics

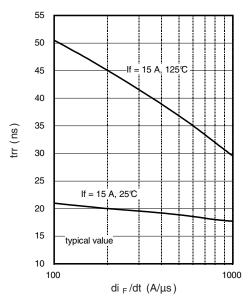


Fig. 7 - Typical Reverse Recovery vs. dl<sub>F</sub>/dt

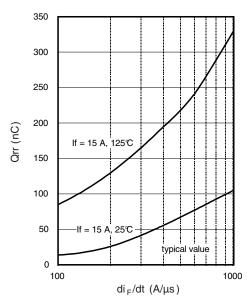
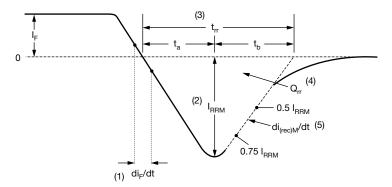


Fig. 8 - Typical Stored Charge vs. dl<sub>F</sub>/dt



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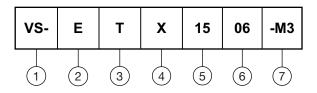


- di<sub>F</sub>/dt rate of change of current through zero crossing
- (4)  $Q_{rr}$  area under curve defined by  $t_{rr}$  and  $I_{RRM}$
- (2)  $I_{RRM}$  peak reverse recovery current
- $Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$
- (3) t<sub>rr</sub> reverse recovery time measured from zero crossing point of negative going I<sub>F</sub> to point where a line passing through 0.75 I<sub>RRM</sub> and 0.50 I<sub>RRM</sub> extrapolated to zero current.
- (5)  $di_{(rec)M}/dt$  peak rate of change of current during  $t_b$  portion of  $t_{rr}$

Fig. 9 - Reverse Recovery Waveform and Definitions

#### **ORDERING INFORMATION TABLE**

#### **Device code**



- Vishay Semiconductors product
- **2** Circuit configuration:

E = single

- **3** T = 2L TO-220AC
- X = hyperfast recovery time
- 5 Current code: 15 = 15 A
- Voltage code: 06 = 600 V
- 7 Environmental digit:
  - -M3 = halogen-free, RoHS-compliant, and terminations lead (Pb)-free

ORDERING INFORMATION (Example)									
PREFERRED P/N BASE QUANTITY PACKAGING DESCRIPTION									
VS-ETX1506-M3	50	Antistatic plastic tubes							

LINKS TO RELATED DOCUMENTS								
Dimensions	www.vishay.com/doc?96156							
Part marking information	www.vishay.com/doc?95391							



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### **TO-220AC 2L**

#### **DIMENSIONS** in millimeters and inches





Conforms to JEDEC® outline TO-220AC

SYMBOL	MILLIMETERS		INC	NCHES NOTES	SYMBOL	MILLIN	IETERS	INC	HES	NOTES		
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES	NOTES	STIVIBOL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.25	4.65	0.167	0.183			D2	11.68	13.30	0.460	0.524	6, 7
A1	1.14	1.40	0.045	0.055			Е	10.11	10.51	0.398	0.414	3, 6
A2	2.50	2.92	0.098	0.115			E1	6.86	8.89	0.270	0.350	6
b	0.69	1.01	0.027	0.040			е	2.41	2.67	0.095	0.105	
b1	0.38	0.97	0.015	0.038	4		e1	4.88	5.28	0.192	0.208	
b2	1.20	1.73	0.047	0.068			H1	6.09	6.48	0.240	0.255	6
b3	1.14	1.73	0.045	0.068	4		L	13.52	14.02	0.532	0.552	
С	0.36	0.61	0.014	0.024			L1	3.32	3.82	0.131	0.150	2
c1	0.36	0.56	0.014	0.022	4		ØΡ	3.54	3.91	0.139	0.154	
D	14.85	15.35	0.585	0.604	3		Q	2.60	3.00	0.102	0.118	
D1	8.38	9.02	0.330	0.355				•	•			

#### **Notes**

- <sup>(1)</sup> Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Lead dimension and finish uncontrolled in L1
- (3) Dimension D, D1, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (4) Dimension b1, b3, and c1 apply to base metal only
- Controlling dimensions: inches
- (6) Thermal pad contour optional within dimensions E, H1, D2, and E1
- (7) Outline conforms to JEDEC® TO-220, except D2



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